

10/634,917



Docket No.: 241189US2S



ATTORNEYS AT LAW

COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

RE: Inventor: Wataru SAITO, et al.

Patent No.: 6,940,090 *B2*

Issued: September 6, 2005

Group Art Unit: 2822

Examiner: LEWIS, Monica

For: A WIDEBAND GAP POWER SEMICONDUCTOR
DEVICE HAVING A LOW ON-RESISTANCE AND
HAVING A HIGH AVALANCHE CAPABILITY
USED FOR POWER CONTROL.

SIR:

Attached hereto for filing are the following papers:

REQUEST FOR CERTIFICATE OF CORRECTION
CERTIFICATE OF CORRECTION FORM PTO 1050

Our check in the amount of \$0.00 is attached covering any required fees. In the event any variance exists between the amount enclosed and the Patent Office charges for filing the above-noted documents, including any fees required under 37 C.F.R. 1.136 for any necessary Extension of Time to make the filing of the attached documents timely, please charge or credit the difference to our Deposit Account No. 15-0030. A duplicate copy of this sheet is enclosed.

Respectfully submitted,

OBLON, SPIVAK, McCLELLAND,
MAIER & NEUSTADT, P.C.

Joseph Scafetta Jr.
Marvin J. Spivak

Registration No. 24,913

Joseph Scafetta, Jr.

Registration No. 26,803

Customer Number

22850

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(OSMMN 05/04)

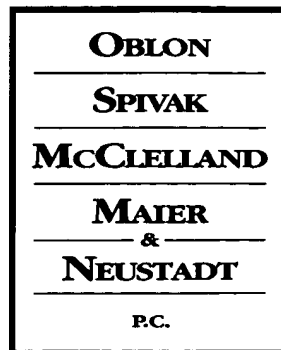
Certificate
NOV 01 2005
of Correction

NOV 02 2005



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NOV 02 2005

DOCKET NO.: 241189US2S/amr



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN RE APPLICATION OF: Wataru SAITO, et al.

PATENT NO.: 6,940,090 B2

GROUP: 2822

ISSUED: September 6, 2005

EXAMINER: LEWIS, Monica

FOR: A WIDEBAND GAP POWER SEMICONDUCTOR DEVICE HAVING A LOW ON-RESISTANCE AND HAVING A HIGH AVALANCHE CAPABILITY USED FOR POWER CONTROL.

REQUEST FOR CERTIFICATE OF CORRECTION

DIRECTOR OF THE UNITED STATES PATENT AND TRADEMARK OFFICE
ALEXANDRIA, VA 22313-1450

SIR:

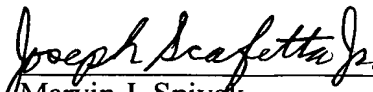
The following is a Request for a Certificate of Correction in Serial Number 10/634,917, now Patent Number 6,940,090.

In accordance with the provisions of Rule 322 of the Rules of Practice, which implement 35 USC 254, the Patent & Trademark Office is respectfully requested to issue a Certificate of Correction in the above-identified patent.

In light of the fact that the errors were the fault of the Patent & Trademark Office, no fees are required. The requested corrections are listed on FORM P.T.O. 1050.

Respectfully submitted,

OBLON, SPIVAK, McCLELLAND,
MAIER & NEUSTADT, P.C.


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Registration No. 24,913

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NOV 02 2005

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : **6,940,090 B2**
DATED: **Sep. 6, 2005**
INVENTOR(S): **Saito et al.**

It is certified that an error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

On the title page, Item (54) and Column 1, the Title is incorrect. Item (54) and Column 1 should read:

-- (54) A WIDEBAND GAP POWER SEMICONDUCTOR DEVICE HAVING A LOW ON-RESISTANCE AND HAVING A HIGH AVALANCHE CAPABILITY USED FOR POWER CONTROL.--

Mailing address of sender:

Patent No. **6,940,090**

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NOV 02 2005

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 6,940,090 $\beta 2$

DATED: Sep. 6, 2005

INVENTOR(S): Saito et al.

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Patent No. 6,940,090

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